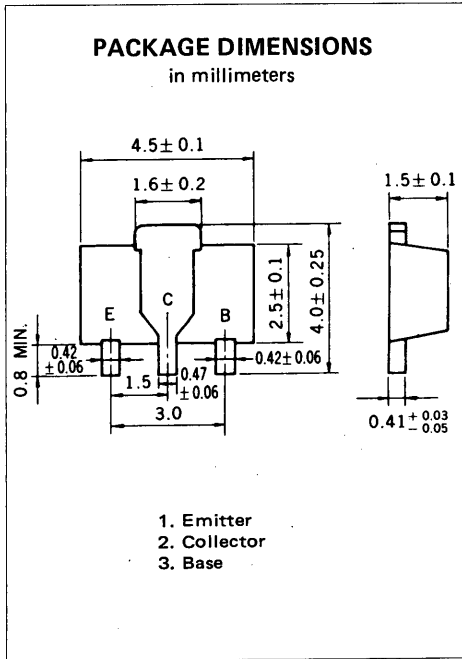


**HIGH SPEED SWITCHING
PNP SILICON EPITAXIAL TRANSISTOR
POWER MINI MOLD**



DESCRIPTION The 2SA1463 is designed for power amplifier and high speed switching applications.

- FEATURES**
- High speed, high voltage switching.
 - Low Collector Saturation Voltage.
 - Complementary to the NEC 2SC3736 NPN transistor.

ABSOLUTE MAXIMUM RATINGS

Maximum Voltages and Currents ($T_a = 25^\circ\text{C}$)

Collector to Base Voltage	V_{CB0}	-60	V
Collector to Emitter Voltage	V_{CEO}	-45	V
Emitter to Base Voltage	V_{EBO}	-5.0	V
Collector Current (DC)	I_C	-1.0	A
Collector Current (Pulse)*	I_C	-2.0	A
Maximum Power Dissipation			
Total Power Dissipation			
at 25°C Ambient Temperature**	P_T	2.0	W
Maximum Temperatures			
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-55 to +150	$^\circ\text{C}$

* $PW \leq 10$ ms, Duty Cycle ≤ 50 %

** When mounted on ceramic substrate of $16\text{ cm}^2 \times 0.7$ mm

ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

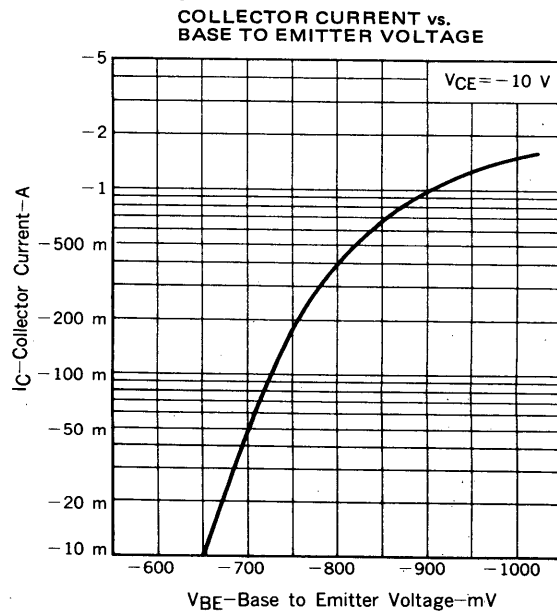
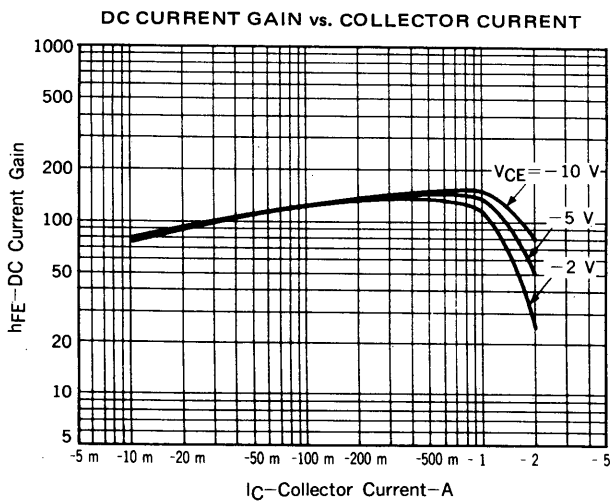
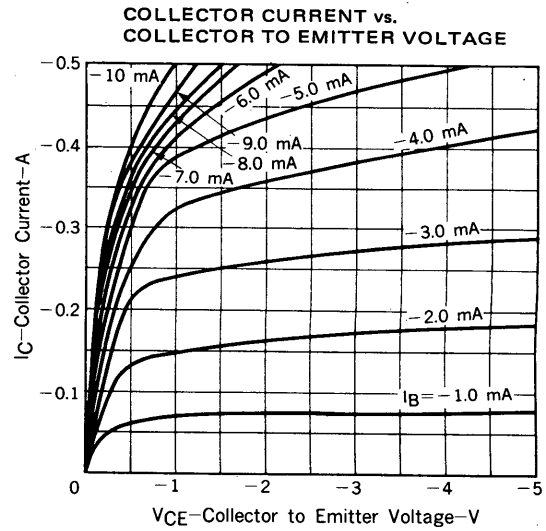
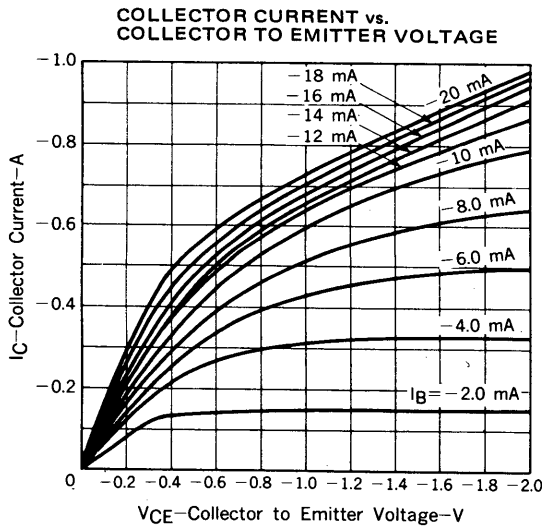
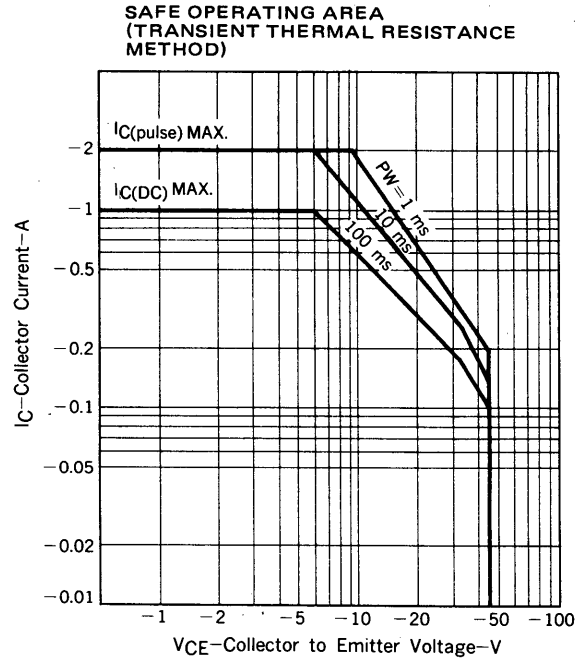
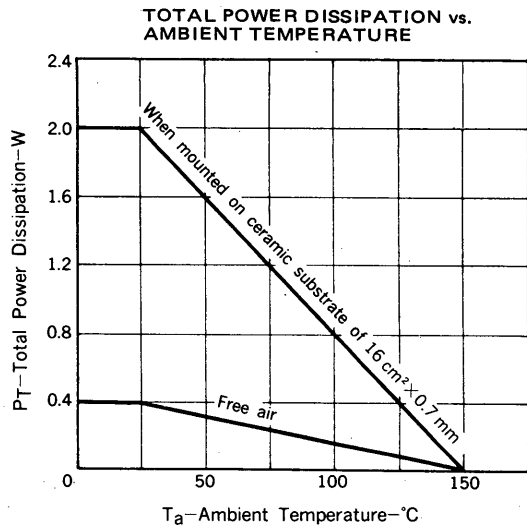
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Collector Cutoff Current	I_{CES}			-0.5	μA	$V_{CE} = -45\text{ V}, R_{BE} = 0$
Emitter Cutoff Current	I_{EBO}			-0.5	μA	$V_{EB} = -4.0\text{ V}, I_C = 0$
DC Current Gain	h_{FE1}^{***}	60		200		$V_{CE} = -10\text{ V}, I_C = -50\text{ mA}$
DC Current Gain	h_{FE2}^{***}	60				$V_{CE} = -10\text{ V}, I_C = -500\text{ mA}$
Collector Saturation Voltage	$V_{CE(sat)}^{***}$		-0.26	-0.6	V	$I_C = -500\text{ mA}, I_B = -50\text{ mA}$
Base Saturation Voltage	$V_{BE(sat)}^{***}$		-0.98	-1.2	V	
Gain Bandwidth Product	f_T	300	400		MHz	$V_{CE} = -10\text{ V}, I_E = 100\text{ mA}$
Output Capacitance	C_{ob}		11	25	pF	$V_{CB} = -10\text{ V}, I_E = 0, f = 1.0\text{ MHz}$
Turn-on Time	t_{on}		25	40	ns	$I_C = -500\text{ mA}$ $I_{B1} = -I_{B2} = -50\text{ mA}$
Storage Time	t_{stg}		46	70	ns	
Turn-off Time	t_{off}		62	100	ns	

***Pulsed: $PW \leq 350\ \mu\text{s}$, Duty Cycle ≤ 2 %

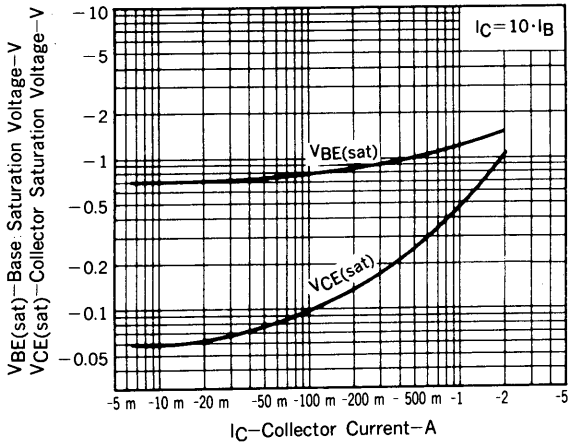
h_{FE} Classification

MARKING	IL	IK
h_{FE}	60 to 120	100 to 200

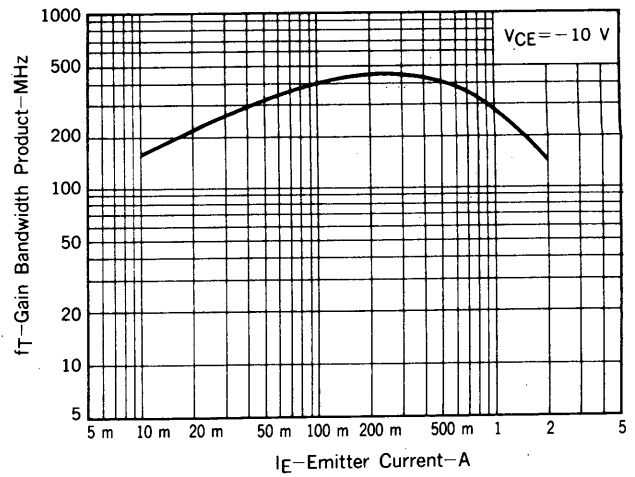
TYPICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)



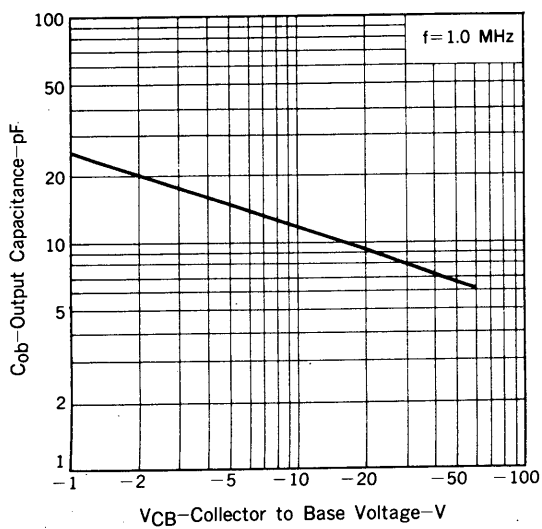
BASE AND COLLECTOR SATURATION VOLTAGE vs. COLLECTOR CURRENT



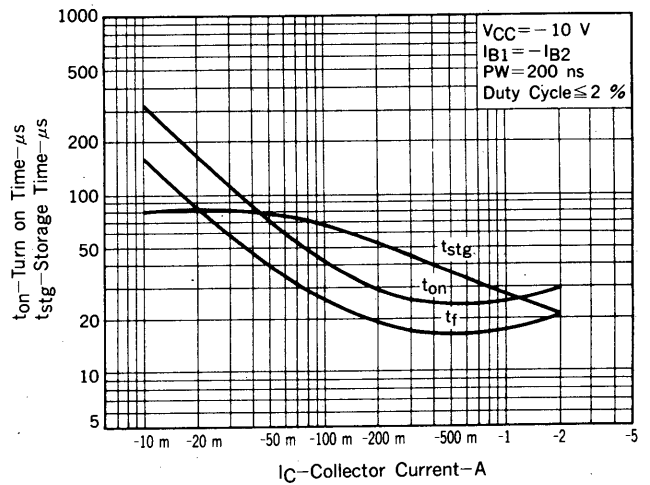
GAIN BANDWIDTH PRODUCT vs. EMITTER CURRENT



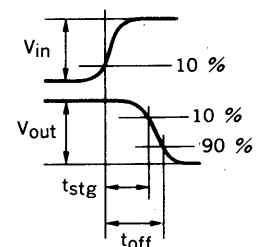
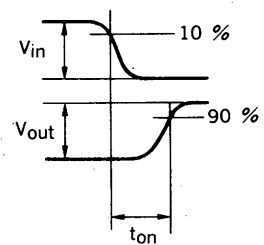
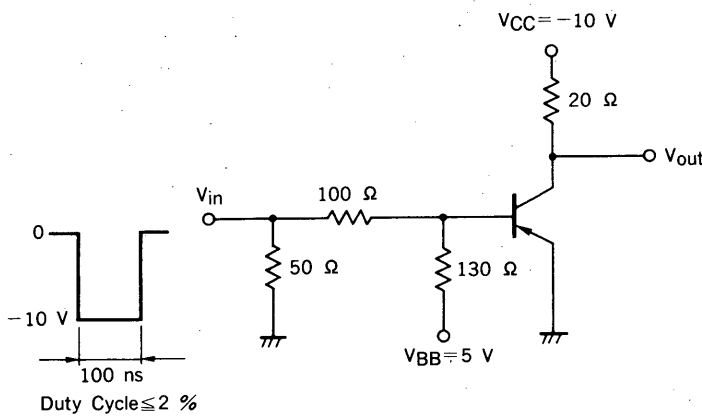
OUTPUT CAPACITANCE vs. REVERSE VOLTAGE



SWITCHING TIME vs. COLLECTOR CURRENT



SWITCHING TIME TEST CIRCUIT



REFERENCE

Document Name	Document No.
NEC semiconductor device reliability/quality control system.	TEI-1202
Quality grade on NEC semiconductor devices.	IEI-1209
Semiconductor device mounting technology manual.	IEI-1207
Semiconductor device package manual.	IEI-1213
Guide to quality assurance for semiconductor devices.	MEI-1202
Semiconductor selection guide.	MF-1134

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